ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to GND

V+	0.3V to +44V
V	+0.3V to -44V
V+ to V	-0.3V to +44V
VL	(GND - 0.3V) to (V+ + 0.3V)
	(V 2V) to (V+ + 2V)
C	or 30mA (whichever occurs first)
Continuous Current (COM_, NO	_, NC_)±100mA
Peak Current (COM_, NO_, NC_	_)±300mA

Continuous Power Dissipation ($T_A = +70^{\circ}C$)
Plastic DIP (derate 10.53mW/°C above +70°C)842mW
Narrow SO (derate 8.70mW/°C above +70°C)
CERDIP (derate 10.00mW/°C above +70°C)800mW
TSSOP (derate 6.7mW/°C above +70°C)457mW
Operating Temperature Ranges
MAX31_C0°C to +70°C
MAX31_E40°C to +85°C
MAX31_M55°C to +125°C
Storage Temperature Range65°C to +150°C
Lead Temperature (soldering, 10s)+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note 1: Signals on NC_, NO_, COM_, or IN_ exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current rating.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = 15V, V- = -15V, VL = 5V, GND = 0V, VINH = 2.4V, VINL = 0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP (Note 2)	MAX	UNITS	
ANALOG SWITCH									
Analog Signal Range	V _{COM} _, V _{NO} _, V _{NC} _	(Note 3)		V-		V+	V		
		10m	T _A =	С, Е		6.5	10		
On-Resistance	Ron	$I_{COM} = 10 \text{mA},$ $V_{NO_} \text{ or } V_{NC_} = \pm 10 \text{V}$	+25°C	Μ			9	Ω	
			T _A = T _{MIN}	to T _{MAX}			15		
On-Resistance Match Between	ΔRon	$I_{COM} = 10 mA,$	T _A = +25°	С		0.3	1.5	Ω	
Channels (Note 4)	ANON	V_{NO} or V_{NC} = ±10V	V_{NO} or V_{NC} = ±10 V T _A = T _{MIN} to T _{MAX}				3	52	
On-Resistance Flatness			$I_{COM} = 10 \text{mA}, \qquad T_{A} = +25^{\circ}\text{C}$			0.2	2		
(Note 5)	R _{FLAT} (ON)	V _{NO} _ or V _{NC} _ = -5V, 0V, 5V	T _A = T _{MIN}	to T _{MAX}			4	Ω	
Off Leakage Current		1014	TA = +25°	С	-0.5	-0.02	0.5		
(NO_ or NC_)	INO INC	$V_{COM} = \pm 10V,$ V_{NO} or $V_{NC} = \pm 10V$	T _A = T _{MIN}	C, E	-2.5		2.5	nA	
(Note 6)	inc		to T _{MAX}	М	-40		40		
			T _A = +25°	Ċ	-0.5	-0.02	0.5		
COM Off Leakage Current (Note 6)	INC(OFF)	$V_{COM} = \pm 10V,$ V_{NO} or $V_{NC} = \pm 10V$	T _A = T _{MIN}	C, E	-2.5		2.5	nA	
			to TMAX	М	-40		40		
		101/	T _A = +25°	Ċ	-1	-0.04	1		
COM On Leakage Current (Note 6)	ICOM(ON)	$V_{COM} = \pm 10V,$ $V_{NO_{-}} \text{ or } V_{NC_{-}} = \pm 10V$	T _A = T _{MIN}	C, E	-5		5	nA	
			to T _{MAX}	М	-100		100		

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

 $(V + = 15V, V - = -15V, VL = 5V, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
LOGIC INPUT							
Input Current with Input Voltage High	IINH	$IN_= 2.4V$, all others = 0.8V		-0.500	0.005	0.500	μA
Input Current with Input Voltage Low	IINL	IN_ = 0.8V, all others =	: 2.4V	-0.500	0.005	0.500	μA
POWER SUPPLY		1		-			
Power-Supply Range				±4.5		±20.0	V
Positive Supply Current	I+	All channels on or off, $V_{IN} = 0V$ or 5V,	$T_A = +25^{\circ}C$	-1	0.0001	1	μA
		V+ = 16.5V V- = -16.5V	$T_A = T_{MIN}$ to T_{MAX}	-5		5	
Negative Supply Current	-	All channels on or off, VIN = 0V or 5V,	T _A = +25°C	-1	0.0001	1	μA
nogativo ouppiy ouriont		V+ = 16.5V V- = -16.5V	$T_A = T_{MIN}$ to T_{MAX}	-5		5	μ
Logic Supply Current	h	All channels on or off, VIN = 0V or 5V,	T _A = +25°C	-1	0.0001	1	- μΑ
Logic Supply Current		V+ = 16.5V V- = -16.5V	$T_A = T_{MIN}$ to T_{MAX}	-5		5	
Ground Current IGND		All channels on or off, $V_{IN} = 0V \text{ or } 5V,$ $V_{+} = 16.5V$ $V_{-} = -16.5V$	T _A = +25°C	-1	-0.0001	1	— μΑ
	GND		$T_A = T_{MIN}$ to T_{MAX}	-5		5	
DYNAMIC	1		1				
Turn-On Time	ton	Figure 2, V _{COM} = ±10V	$T_A = +25^{\circ}C$		70	225	ne
			$T_A = T_{MIN}$ to T_{MAX}			275	– ns
Turn-Off Time	torr	Figure 2,	$T_A = +25^{\circ}C$		65	185	20
	toff	$V_{COM} = \pm 10V$	$T_A = T_{MIN}$ to T_{MAX}			235	ns
Break-Before-Make Time Delay	tD	$\begin{array}{l} \mbox{MAX314 only, Figure 3,} \\ \mbox{R}_L = 300\Omega, \\ \mbox{C}_L = 35 \mbox{pF} \end{array}$	T _A = +25°C	1	5		ns
Charge Injection (Note 3)	VCTE	$C_L = 1.0$ nF VGEN = 0V, RGEN = 0 Ω , Figure 4	T _A = +25°C	-30	20	30	рС
Off Isolation (Note 7)	V _{ISO}	$\begin{array}{l} R_{L}=50\Omega,\\ C_{L}=5pF,\\ f=1MHz,Figure5 \end{array}$	T _A = +25°C		-65		dB
Crosstalk (Note 8)	V _{CT}	$\begin{array}{l} R_{L}=50\Omega,\\ C_{L}=5pF,\\ f=1MHz,\ Figure\ 6 \end{array}$	T _A = +25°C		-85		dB
NC or NO Capacitance	C(OFF)	f = 1MHz, Figure 7	T _A = +25°C		15		pF
COM Off Capacitance	C(COM)	f = 1MHz, Figure 7	$T_A = +25^{\circ}C$		15		pF
On Capacitance	C(COM)	f = 1MHz, Figure 7	T _A = +25°C		47		рF



ELECTRICAL CHARACTERISTICS—Single Supply

 $(V + = 12V, V - = 0V, VL = 5V, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, T_A = T_{MIN}$ to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS	
ANALOG SWITCH	1			1			1	
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}	(Note 3)		0		V+	V	
Channel On-Resistance	Ron	$I_{COM} = 10 \text{mA},$	$T_A = +25^{\circ}C$		12.5	25	Ω	
		V _{NC} or V _{NO} +10V	$T_A = T_{MIN}$ to T_{MAX}			35		
POWER SUPPLY		1						
Positive Supply Current	+	V + = 13.2V all channels on or off.	$T_A = +25^{\circ}C$	-1	0.0001	1	- μΑ	
	17	$V_{\rm IN} = 0V \text{ or } 5V$	$T_A = T_{MAX}$	-5		5		
La sia Quera la Quera st	١L	$\label{eq:VL} \begin{array}{l} V_L = 5.5V\\ \text{all channels on or off,}\\ V_{IN} = 0V \text{ or } 5V \end{array}$	$T_A = +25^{\circ}C$	-1	0.0001	1	- μΑ	
Logic Supply Current			T _A = T _{MAX}	-5		5		
	1.	$V_{L} = 5.5V$	T _A = +25°C	-1	-0.0001	1		
Ground Current	IGND	all channels on or off, V _{IN} = 0V or 5V	T _A = T _{MAX}	-5		5	μΑ	
DYNAMIC	1	I						
Turn-On Time	ton	Figure 2,	$T_A = +25^{\circ}C$		100	325	ns	
(Note 3)	1011	V_{NO} or V_{NC} = 8V	$T_A = T_{MIN}$ to T_{MAX}			425	110	
Turn-Off Time	toff	Figure 2,	$T_A = +25^{\circ}C$		95	175	- ns	
(Note 3)	10FF	V_{NO} or V_{NC} = 8V	$T_A = T_{MIN}$ to T_{MAX}			225	115	
Break-Before-Make Time Delay (Note 3)	tD	$\begin{array}{l} \mbox{MAX314 only, Figure 3} \\ \mbox{R}_L = 300\Omega, \\ \mbox{C}_L = 35 \mbox{pF} \end{array}$	$T_A = +25^{\circ}C$		5		ns	
Charge Injection (Note 3)	VCTE	Figure 4, $C_L = 1.0nF$, $V_{GEN} = 0V$, $R_{GEN} = 0V$	T _A = +25°C		-5		рС	

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

Note 3: Guaranteed by design.

Note 4: $\Delta R_{ON} = \Delta R_{ON} \max - \Delta R_{ON} \min$.

Note 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal range.

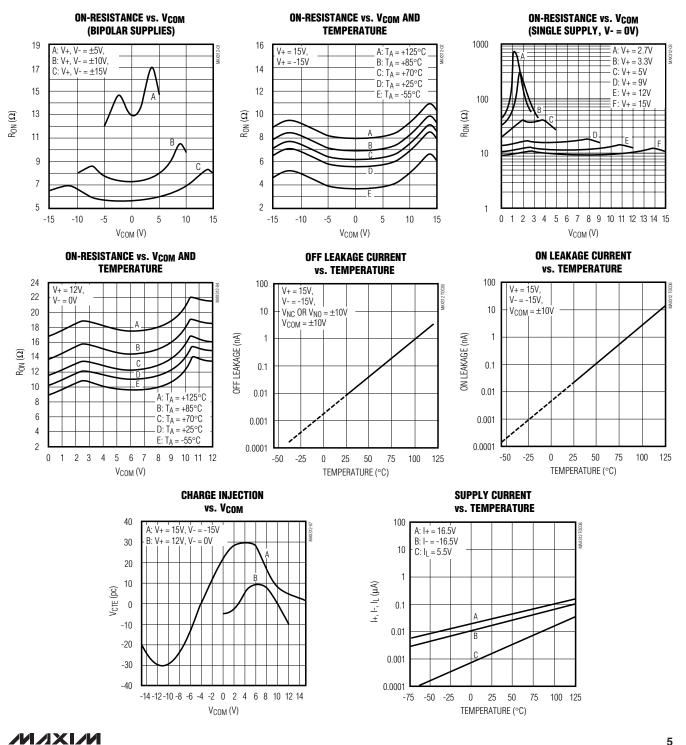
Note 6: Leakage parameters are 100% tested at maximum-rated hot temperature and guaranteed by correlation at +25°C.

Note 7: Off isolation = $20\log_{10} [V_{COM} / (V_{NC} \text{ or } V_{NO})], V_{COM} = \text{output}, V_{NC} \text{ or } V_{NO} = \text{input to off switch}.$

Note 8: Between any two switches.

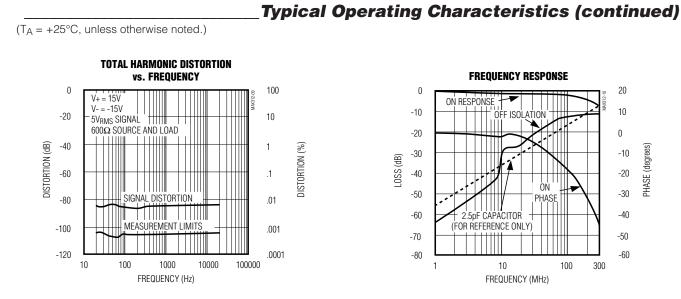
Note 9: Leakage testing at single supply is guaranteed by testing with dual supplies.

Typical Operating Characteristics



MAX312/MAX313/MAX314

 $(T_A = +25^{\circ}C, unless otherwise noted.)$



Pin Description

MIXIM

PIN		NAME	FUNCTION		
MAX312	MAX313	MAX314		FONCTION	
1, 8, 9, 16	1, 8, 9, 16	1, 8, 9, 16	IN2, IN4, IN3, IN2	Logic Level Inputs	
2, 7, 10, 15	2, 7, 10, 15	2, 7, 10, 15	COM1, COM4, COM3, COM2	Analog Signal Common Terminals	
3, 6, 11, 14			NC1, NC4, NC3, NC2	Analog Signal Normally Closed Terminals	
	3, 6, 11, 14		NO1, NO4, NO3, NO2	Analog Signal Normally Open Terminals	
_	_	3, 6	NO1, NO4	Analog Signal Normally Open Terminals	
_		11, 14	NC3, NC2	Analog Signal Normally Closed Terminals	
4	4	4	V-	Negative Analog Supply Input (connect to GND for single-supply operation)	
5	5	5	GND	Logic Level Ground	
12	12	12	VL	Logic Supply Voltage	
13	13	13	V+	Positive Analog Supply Input	

Applications Information

Low-Distortion Audio

The MAX312/MAX313/MAX314, having very low R_{ON} and very low R_{ON} variation with signal amplitude, are well suited for low-distortion audio applications. The *Typical Operating Characteristics* show Total Harmonic Distortion (THD) vs. Frequency graphs for several signal amplitudes and impedances. Higher source and load impedances improve THD, but reduce off isolation.

Off Isolation at High Frequencies

In 50 Ω systems, the high-frequency on-response of these parts extends from DC to above 100MHz with a typical loss of -2dB. When the switch is turned off, however, it behaves like a capacitor, and off isolation decreases with increasing frequency. (Above 300MHz, the switch actually passes more signal turned off than turned on.) This effect is more pronounced with higher source and load impedances.

Above 5MHz, circuit board layout becomes critical, and it becomes difficult to characterize the response of the switch independent of the circuit. The graphs shown in the *Typical Operating Characteristics* were taken using a 50 Ω source and load connected with BNC connec-

tors to a circuit board deemed "average"; that is, designed with isolation in mind, but not using strip-line or other special RF circuit techniques. For critical applications above 5MHz, use the MAX440, MAX441, and MAX442, which are fully characterized up to 160MHz.

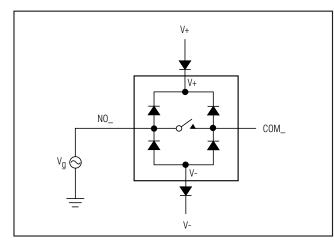


Figure 1. Overvoltage Protection Using External Blocking Diodes

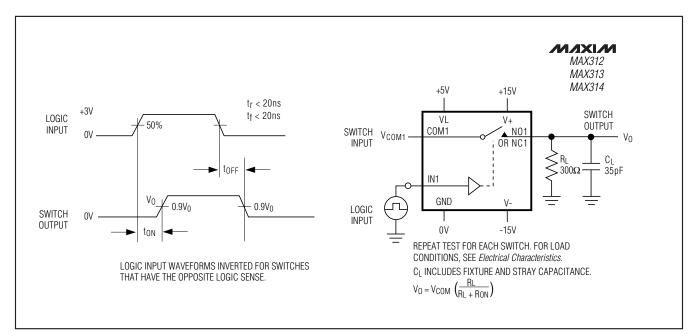
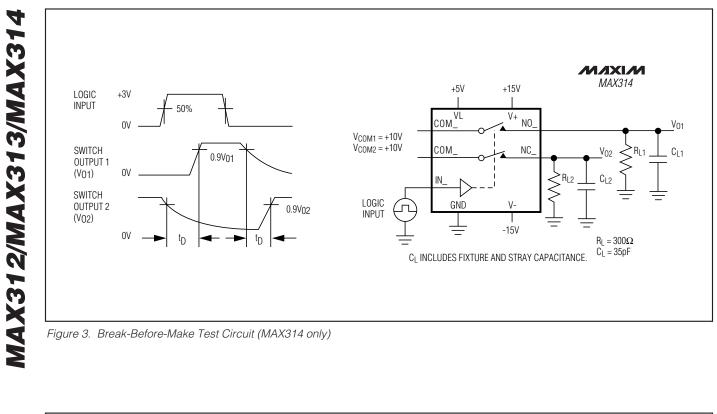


Figure 2. Switching-Time Test Circuit

MAX312/MAX313/MAX314



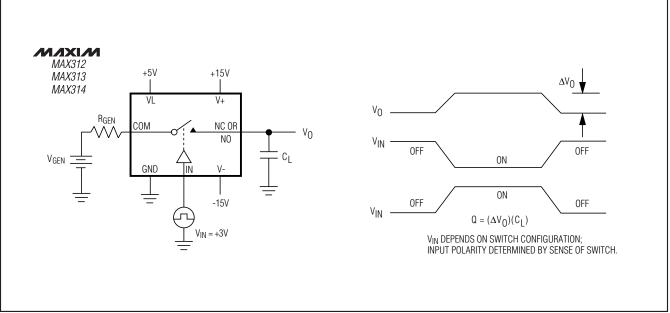


Figure 4. Charge Injection Test Circuit

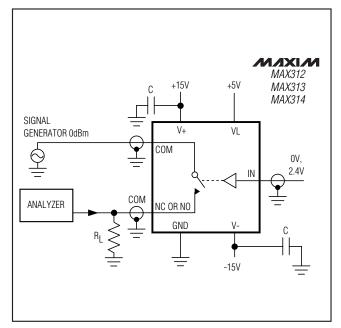


Figure 5. Off-Isolation Test Circuit

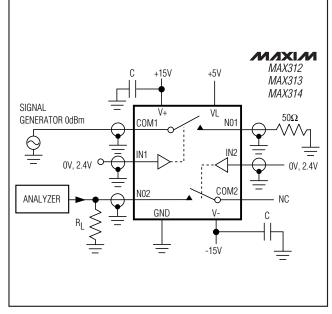


Figure 6. Crosstalk Test Circuit

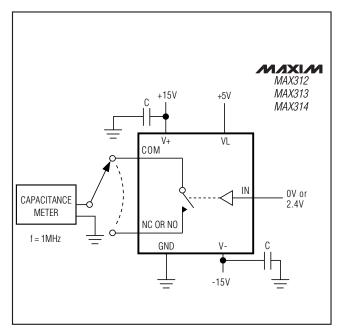
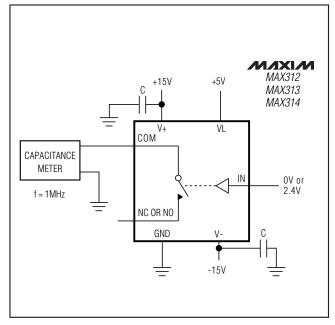


Figure 7. Channel-Off Capacitance Test Circuit



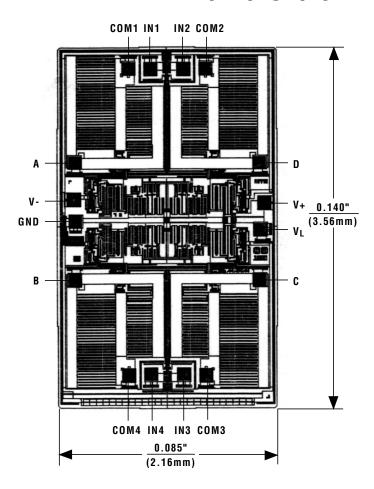


	•	. ,
PART	TEMP. RANGE	PIN-PACKAGE
MAX313CPE	0°C to +70°C	16 Plastic DIP
MAX313CSE	0°C to +70°C	16 Narrow SO
MAX313CUE	0°C to +70°C	16 TSSOP
MAX313C/D	0°C to +70°C	Dice*
MAX313EPE	-40°C to +85°C	16 Plastic DIP
MAX313ESE	-40°C to +85°C	16 Narrow SO
MAX313EUE	-40°C to +85°C	16 TSSOP
MAX313MJE	-55°C to +125°C	16 CERDIP**
MAX314CPE	0°C to +70°C	16 Plastic DIP
MAX314CSE	0°C to +70°C	16 Narrow SO
MAX314CUE	0°C to +70°C	16 TSSOP
MAX314C/D	0°C to +70°C	Dice*
MAX314EPE	-40°C to +85°C	16 Plastic DIP
MAX314ESE	-40°C to +85°C	16 Narrow SO
MAX314EUE	-40°C to +85°C	16 TSSOP
MAX314MJE	-55°C to +125°C	16 CERDIP**

* Contact factory for dice specifications. **Contact factory for availability.

Ordering Information (continued)

Chip Topography



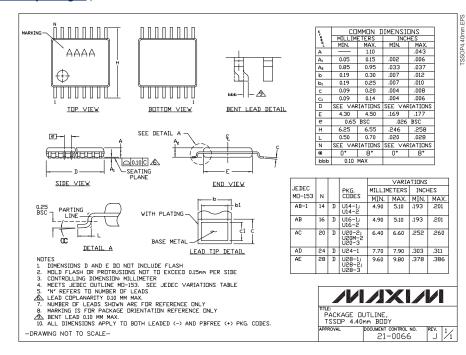
MAX	(312	MAX313		MAX	(314
PIN	NAME	PIN	NAME	PIN	NAME
A	NC1	А	NO1	А	NO1
В	NC4	В	NO4	В	NO4
С	NC3	С	NO3	С	NC3
D	NC2	D	NO2	D	NC2

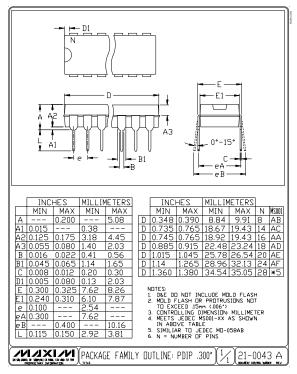
MIXIM

TRANSISTOR COUNT: 100 SUBSTRATE CONNECTED TO V+

Package Information

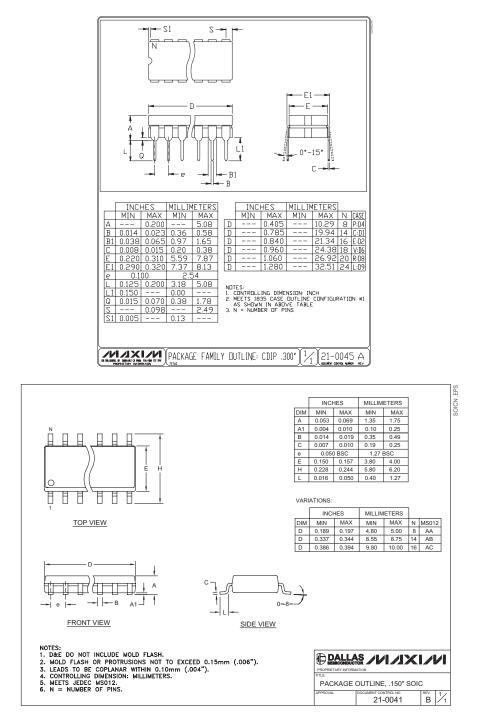
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to <u>www.maxim-ic.com/packages</u>.)





Package Information (continued)

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